

Atomic Force Microscope (AFM) Dimension 3000 utilizes standard and advanced AFM imaging modes to measure surface topography and characteristics for semiconductors, lithography masks, magnetic media, CDs/DVDs, biomaterials and other samples up to 200mm in diameter.

The AFM uses a nano-sized tip mounted on a flexible cantilever which scans above the surface to be investigated. Interatomic forces between tip and sample surface induce bending of the cantilever. A laser beam is reflected from the cantilever and is detected with a position sensitive detector which provides topographical image of the surface with atomic resolution. The cantilever can be deflected not only by far-ranging forces but also electric, magnetic, and other forces. It provides researchers the advanced scanning probe microscopy modes:

- AFM Phase Image
- Electric Force Microscopy (EFM)
- Scanning Capacitance Microscopy (SCM)
- Scanning Tunneling Microscopy (STM)

The AFM is capable of resolving single atomic steps on epitaxial thin films and measuring sub-Angstrom surface roughness on ultrasmooth surfaces.

AFM Dimension 3100 Basic specifications:

- X-Y Scan Range ~90µm square
- Z Range $\leq 4.6 \mu m$
- Sample Size ≤ 200 mm (with optional chuck)
- Sample Holders 150mm vacuum chuck for hard disks, semiconductor wafers, and other samples
 - magnetic holder for smaller samples up to 6mm thick
- Inspectable scanning area: 100µm x 100µm
- Vibration Isolation table and Silicone vibration pad

USF College of Engineering 4202 East Fowler Avenue NTA102 Tampa, Florida 33620-5350 Contact: Dr. Yusuf Emirov Cell: 813.390.1652 Fax: 813.974.3610 http://www.nrec.usf.edu



- Magnetic Force Microscopy (MFM)
- Force Modulation
- Lateral Force Microscopy (LFM)